GUZIK PRODUCT BULLETIN

MR7 READ/WRITE AMPLIFIER





- 3 GHz Low-Impedance Current Sense Read Amplifier
- 4 Gbit/sec Write Data Speed
- 100 psec Rise/Fall Time of Write Current
- Programmable Width and Amplitude of Overshoot
- Write-to-Read and Read-to-Write Recovery Time below 100 nsec
- Programmable Heater Control
- Microactuator Support

Guzik MR7 amplifier is designed for high-speed operation with RWA-2000 series. Compared with MR5 head amplifier, it has much wider bandwidth of write and read channels and significantly faster rise/fall time of write current. As a result, the MR7 can operate with data speed up to 4 Gbit/sec.

The output impedance of the MR7 write driver is 60 Ohm differential. The impedance can be changed per customer request to match a write-head specification. Since the read amplifier of the MR7 is a low-impedance current sense amplifier, the MR7 can work with both TMR and GMR types of magnetic heads.



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MR7 Read/Write Amplifier Specifications:

Write Driver

- Write data speed: up to 4Gbit/sec
- Rise/fall time of write current (100% overshoot): 100 psec (10-90%)
- Output common mode voltage: less than ±0.1 V
- Write current: programmable 0 to 100 mA (zero to peak)
- **Read-to-write recovery time:** less than 100 nsec
- Head voltage swing: more than 12 V peak to peak
- Programmable overshoot: Amplitude 0 to 100 mA (zero to peak)* Width from 250 psec to 900 psec (PW50)
- **Output impedance:** 60 Ohm differential (contact <u>sales@guzik.com</u> for customer-requested output impedance)

Heater Driver

- Single-ended or differential output configurable on the board upon customer request
- **Output voltage:** from 0 to 12 V (*peak to peak, typical, adjustable upon customer request*)
- Accuracy of output voltage setting: ±10 mV
- **Output current:** up to 125 mA in 0.1 mA steps
- Accuracy of current measurements: ±0.2 mA
- Two types of heater voltage control: Internal control (via 16 bit DAC) separate in the read and the write mode

External control (through MCX connector) with input range from 0 to 3 V and amplification 2 (*typical, adjustable upon customer request*)

- Heater impedance: 50 Ohm or higher
- **Rise/Fall time:** 100 nsec (defined by 4 MHz internal low-pass filter)

Resistance measurements

Read Amplifier

- Differential current sense low-impedance amplifier
- Bandwidth: DC to 3GHz at -3 dB Flatness ±0.5 dB, 0.3 MHz to 2 GHz Group delay flatness ±50 psec to 2 GHz
- Input noise: 1.0 nV / \sqrt{Hz} (typical)
- MR bias voltage: programmable ±400 mV in 0.1 mV steps
- MR Head Impedance: up to 1000 Ohm
- MR impedance measurement accuracy: 1% within the bias voltage range (20 mV to 400 mV)
- **Common mode rejection ratio:** 24 dB (*typical*) in full bandwidth (18 dB minimum at 700 MHz)
- Non linear distortion (1 GHz, 1 mV input level): less than 1%
- Amplification: 30 dB**
- Write-to-read and read-to-write recovery time: 100 nsec (*typical*) for both Bias On and Shut Down Bias modes***
- Input impedance: 80 Ohm differential (*typical*)
- **Guzik MR7 head amplifier compatibility:** with Universal Preamplifier UP10 only.

Microactuator

Single-ended or differential output configurable on the board upon customer request

- * Write current should not exceed 100 mA (zero to peak) for any overshoot value
- ** Required amplification is provided by UP10
- *** Measurements conditions: write current 50 mA, head inductance 5 nH, write data 1 Gbit/sec



MR7 Write Driver Test Setup



Write Current Waveform

Measurement Conditions: write current 50 mA, overshoot amplitude 100%, head equivalent 5 Ohm.



Figure 1: Write current with the minimum and the maximum overshoot width





Figure 2: Write current eye diagram at 4 Gbit/sec, pattern PRBS 1+x⁸+x⁴+x³+x², 100% overshoot, overshoot width 250 psec



Figure 3: Write current eye diagram at 4 Gbit/sec, pattern PRBS 1+x⁸+x⁴+x³+x², no overshoot

